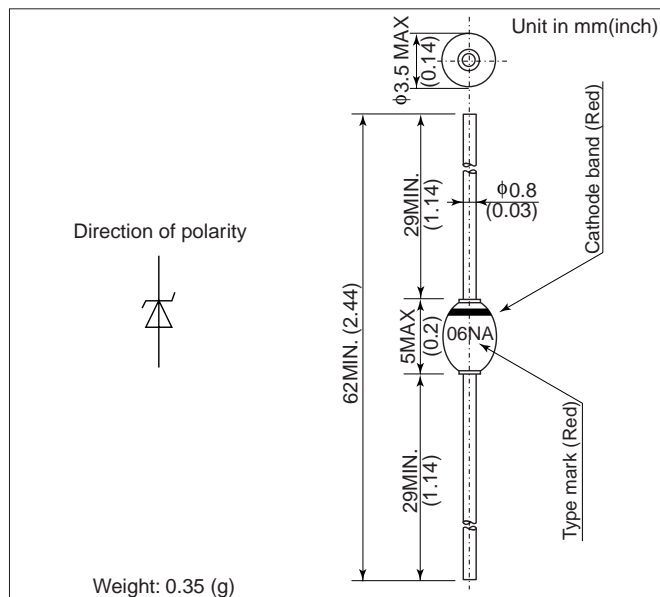


AW01

FEATURES

- For stabilized power supply.
- Diffused-junction. Glass passivated and encapsulated.

OUTLINE DRAWING



ABSOLUTE MAXIMUM RATINGS

| Items | Symbols | Units | Ratings |
|---|------------------|--------------------|---------------------------------|
| Permissible Power Dissipation | P | W | 1.0 |
| Operating Junction Temperature | T_j | $^{\circ}\text{C}$ | -40 ~ +150 |
| Storage Temperature | T_{stg} | $^{\circ}\text{C}$ | -40 ~ +150 |
| Maximum Permissible Current | I_{ZM} | mA | Refer to characteristics column |
| Non-Repetitive Peak Reverse One-Cycle Dissipation | P_{RSM} | Wp | 80 |

Notes (1) Lead mounting : Lead temperature 300 $^{\circ}\text{C}$ max. to 3.2mm from body for 5sec. max..

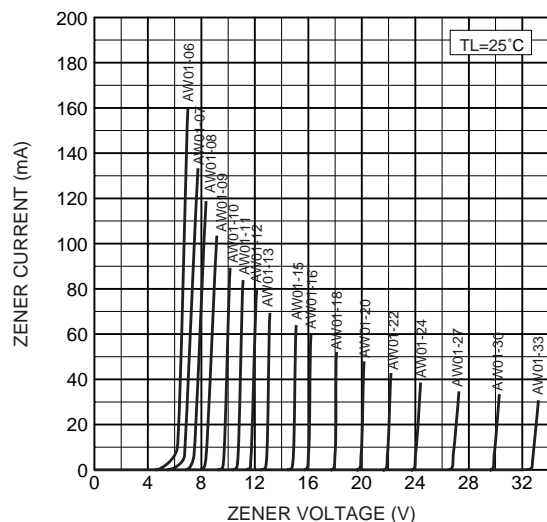
(2) Mechanical strength : Bending 90 $^{\circ}$ ×2 cycles or 180 $^{\circ}$ ×1 cycle, Tensile 2kg, Twist 90 $^{\circ}$ ×1 cycle.

CHARACTERISTICS($T_L=25^{\circ}\text{C}$)

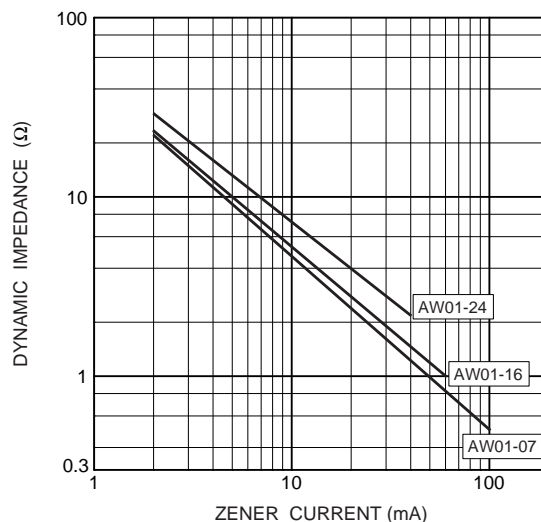
| Type | Characteristics | | | | Maximum Permissible Current (TL=100°C) (L=10mm) I _{ZM} (mA) | Typical Zener Voltage Temperature Coefficient γ _Z (%/°C) |
|---------|----------------------------------|---------|--|----------------------------------|---|--|
| | Zener Voltage V _Z (V) | | Maximum Dynamic Impedance Z _Z (ohm) | Test Current I _Z (mA) | | |
| | Minimum | Maximum | | | | |
| AW01-06 | 5.2 | 6.8 | 9 | 60 | 160 | 0.025 |
| AW01-07 | 6.2 | 7.9 | 7 | 25 | 135 | 0.035 |
| AW01-08 | 7.7 | 8.7 | 3 | 25 | 120 | 0.045 |
| AW01-09 | 8.5 | 9.6 | 3 | 25 | 105 | 0.053 |
| AW01-10 | 9.4 | 10.6 | 5 | 25 | 95 | 0.058 |
| AW01-11 | 10.4 | 11.6 | 5 | 25 | 85 | 0.063 |
| AW01-12 | 11.4 | 12.7 | 8 | 25 | 75 | 0.065 |
| AW01-13 | 12.4 | 14.1 | 8 | 25 | 70 | 0.068 |
| AW01-15 | 13.5 | 15.6 | 12 | 15 | 65 | 0.072 |
| AW01-16 | 15.3 | 17.1 | 12 | 15 | 60 | 0.074 |
| AW01-18 | 16.8 | 19.1 | 15 | 15 | 52 | 0.076 |
| AW01-20 | 18.8 | 21.2 | 15 | 15 | 48 | 0.078 |
| AW01-22 | 20.8 | 23.3 | 15 | 15 | 43 | 0.080 |
| AW01-24 | 22.7 | 25.6 | 15 | 10 | 40 | 0.081 |
| AW01-27 | 25.1 | 28.9 | 15 | 10 | 35 | 0.082 |
| AW01-30 | 28.0 | 32.0 | 15 | 10 | 32 | 0.083 |
| AW01-33 | 31.0 | 35.0 | 15 | 10 | 30 | 0.084 |

AW01

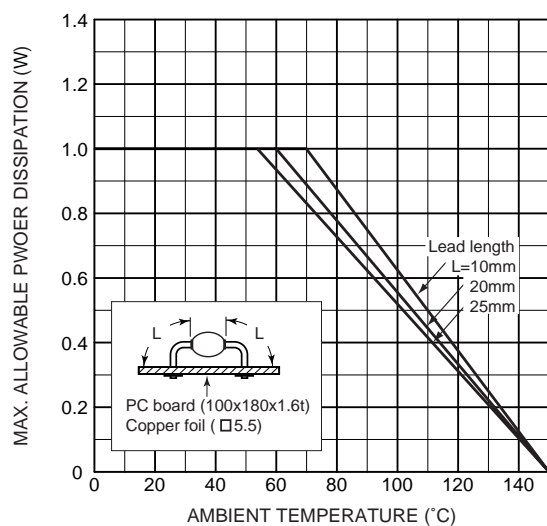
Typical zener characteristics



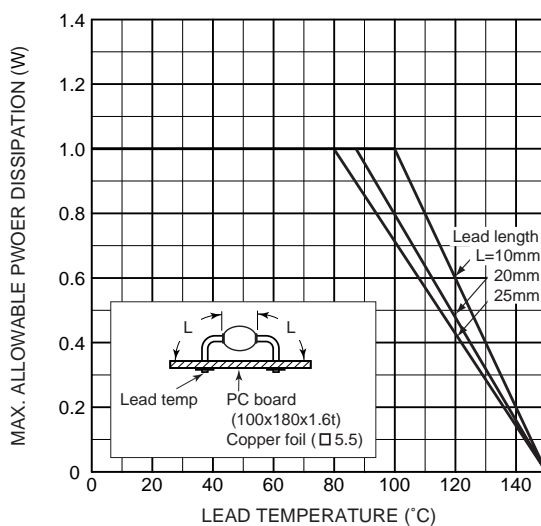
Typical dynamic impedance vs. zener current



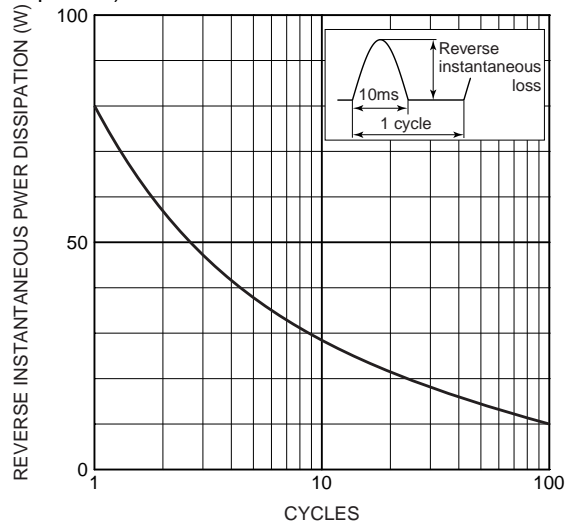
Max. allowable power dissipation vs. ambient temperature



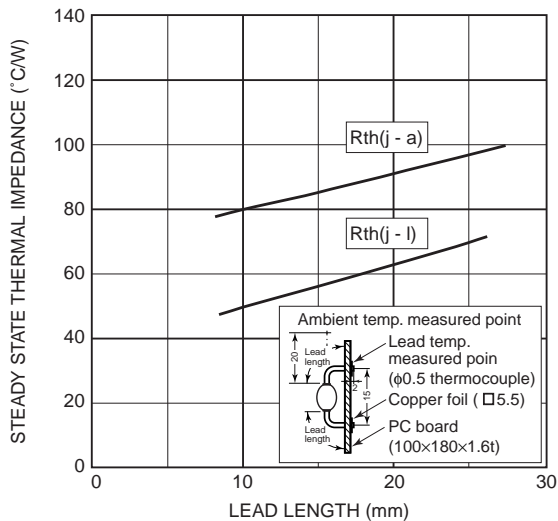
Max. allowable power dissipation vs. lead temperature



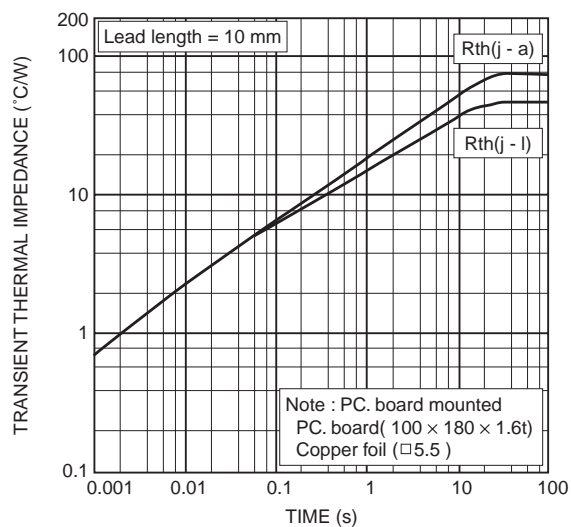
Reverse power characteristic (Non-repetitive)



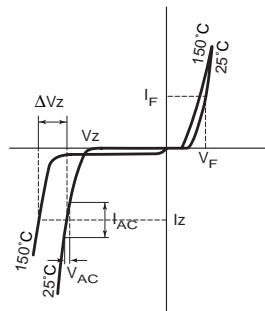
Steady state thermal impedance



Transient thermal impedance



Definition of zener characteristics



ΔV_z : Zener voltage change

V_z : Zener voltage (Test current I_z)

I_z : Test current

Z_z : Dynamic impedance = V_{AC} / I_{AC}

I_F : Forward current

V_F : Forward voltage drop

γ_z : Zener voltage average temperature coefficients

$$= \frac{\Delta V_z}{V_z} \times \frac{1}{(150-25)} \times 100$$

HITACHI POWER SEMICONDUCTORS

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